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Jameco Part Number 1074597



#### **New Product**

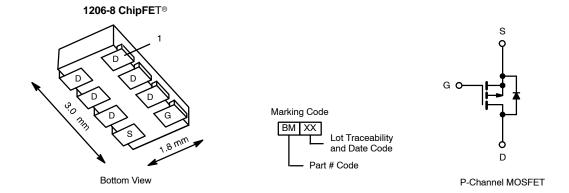
# Vishay Siliconix

# P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$r_{DS(on)}(\Omega)$	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ)		
-8	0.033 @ V <sub>GS</sub> = -4.5 V	-7.1			
	0.043 @ V <sub>GS</sub> = -2.5 V	-6.2	14		
	0.060 @ V <sub>GS</sub> = -1.8 V	-5.3			

#### **FEATURES**

TrenchFET® Power MOSFET



Ordering Information: Si5445BDC-T1—E3

ABSOLUTE MAXIMUM RATING	S (T <sub>A</sub> = 25°C UN	LESS OTHE	RWISE NO	TED)		
Parameter		Symbol	5 secs	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	-8		٧	
Gate-Source Voltage		V <sub>GS</sub>	±8			
Continuous Drain Current (T, = 150°C)a	T <sub>A</sub> = 25°C	. I <sub>D</sub>	-7.1	-5.2	Α	
Continuous Diam Current (1) = 130 C)-	T <sub>A</sub> = 85°C		-5.2	-3.7		
Pulsed Drain Current		I <sub>DM</sub>	± 20		^	
Continuous Source Current <sup>a</sup>		I <sub>S</sub>	-2.1	-1.1		
Mandanian Davis Discipation 8	T <sub>A</sub> = 25°C		2.5	1.3	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 85°C	- P <sub>D</sub>	1.3	0.7		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150			
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>			260		°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 5 sec	_	45	50	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	R <sub>thJA</sub>	85	95		
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	17	20		

- Surface Mounted on 1" x 1" FR4 Board.

  See Reliability Manual for profile. The ChipFET is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder intercon-
- Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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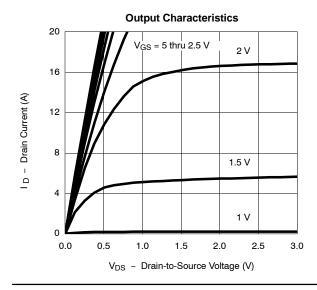


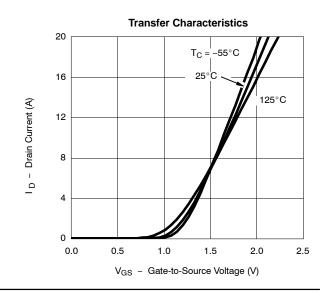
SPECIFICATIONS (T <sub>J</sub> = 25°C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Static			•			•	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -250 \mu A$	-0.45		-1.0	٧	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS}$ = 0 V, $V_{GS}$ = ±8 V			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -8 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = -8 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 85^{\circ}\text{C}$			-1 -5	μΑ	
On-State Drain Currenta	I <sub>D(on)</sub>	$V_{DS} \leq -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-20			Α	
		$V_{GS} = -4.5 \text{ V}, \ I_D = -5.2 \text{ A}$		0.027	0.033		
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	$V_{GS} = -2.5 \text{ V}, I_D = -4.5 \text{ A}$		0.035	0.043	Ω	
		$V_{GS} = -1.8 \text{ V}, I_D = -1.7 \text{ A}$		0.050	0.060		
Forward Transconductancea	9fs	V <sub>DS</sub> = -5 V, I <sub>D</sub> = -5.2 A		18		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = -1.1 A, V <sub>GS</sub> = 0 V		-0.8	-1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			14	21		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -4 \text{ V}, \ V_{GS} = -4.5 \text{ V}, \ I_D = -5.2 \text{ A}$		1.8		nC	
Gate-Drain Charge	Q <sub>gd</sub>			3.3		1	
Gate Resistance	$R_g$	f = 1 MHz		8		Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			12	20	ns	
Rise Time	t <sub>r</sub>	$V_{DD} = -4 \text{ V, } R_L = 4 \Omega$ $I_D \cong -1 \text{ A, } V_{GEN} = -4.5 \text{ V, } R_g = 6 \Omega$		22	35		
Turn-Off Delay Time	t <sub>d(off)</sub>			75	115		
Fall Time	t <sub>f</sub>			50	75	1	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	1 11 4 4 4 4 100 4 4 2		75	115	1	
Reverse Recovery Charge	Q <sub>rr</sub>	$I_F = -1.1 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$		40	60	nC	

- Notes a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%.
- Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



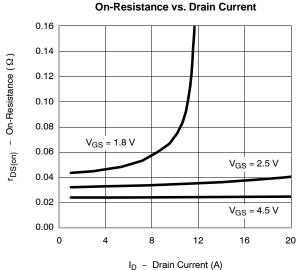


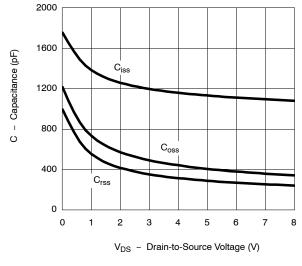




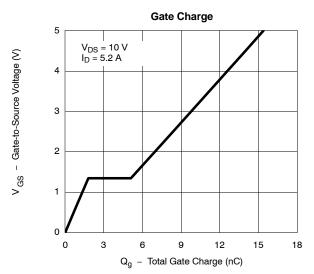
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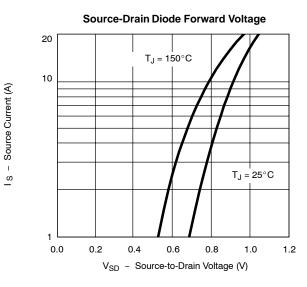
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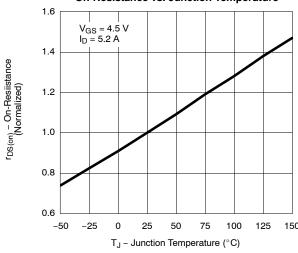


Capacitance

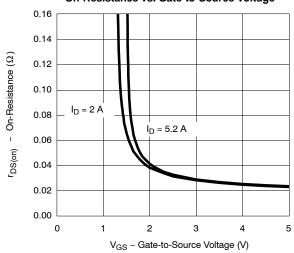




On-Resistance vs. Junction Temperature



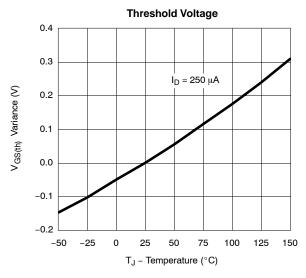
On-Resistance vs. Gate-to-Source Voltage



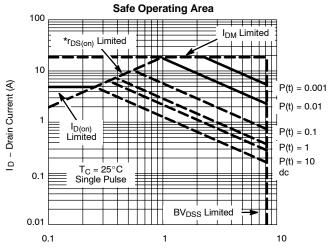
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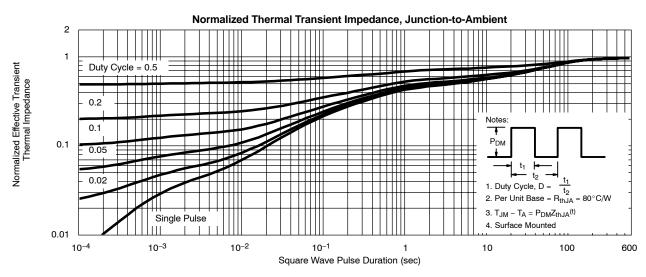
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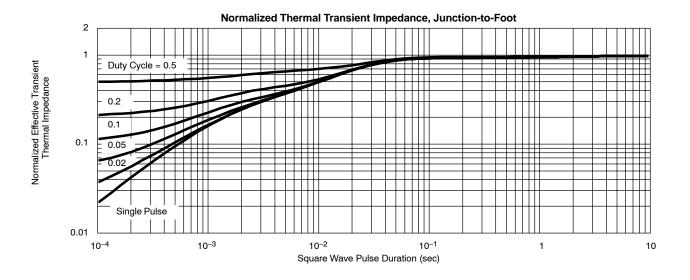




 $\label{eq:VDS} \begin{array}{ll} V_{DS} \ - \ Drain-to-Source \ Voltage \ (V) \\ ^*V_{GS} \ > \ minimum \ V_{GS} \ at \ which \ r_{DS(on)} \ is \ specified \end{array}$ 



### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?73251">http://www.vishay.com/ppg?73251</a>.

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